

NTP75N06, NTB75N06, NTBV75N06

Power MOSFET

75 Amps, 60 Volts, N-Channel
TO-220 and D²PAK

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

Features

- These Devices are Pb-Free and are RoHS Compliant
- NTB75N06 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

Typical Applications

- Power Supplies
- Converters
- Power Motor Controls
- Bridge Circuits

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	60	Vdc
Drain-to-Gate Voltage (R _{GS} = 10 MΩ)	V _{DGR}	60	Vdc
Gate-to-Source Voltage	V _{GS}	±20	Vdc
– Continuous	V _{GS}	±30	Vdc
– Non-Repetitive (t _p ≤ 10 ms)			
Drain Current	I _D	75	Adc
– Continuous @ T _A = 25°C	I _D	50	Adc
– Continuous @ T _A = 100°C	I _{DM}	225	Apk
– Single Pulse (t _p ≤ 10 μs)			
Total Power Dissipation @ T _A = 25°C	P _D	214	W
Derate above 25°C		1.4	W/°C
Total Power Dissipation @ T _A = 25°C		2.4	W
Operating and Storage Temperature Range	T _J , T _{stg}	–55 to +175	°C
Single Pulse Drain-to-Source Avalanche Energy – Starting T _J = 25°C (V _{DD} = 50 Vdc, V _{GS} = 10 Vdc, L = 0.3 mH, I _{L(pk)} = 75 A, V _{DS} = 60 Vdc)	E _{AS}	844	mJ
Thermal Resistance	R _{θJC}	0.7	°C/W
– Junction-to-Case	R _{θJA}	62.5	°C/W
– Junction-to-Ambient			
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	T _L	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

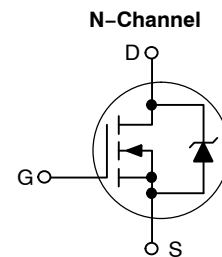


ON Semiconductor®

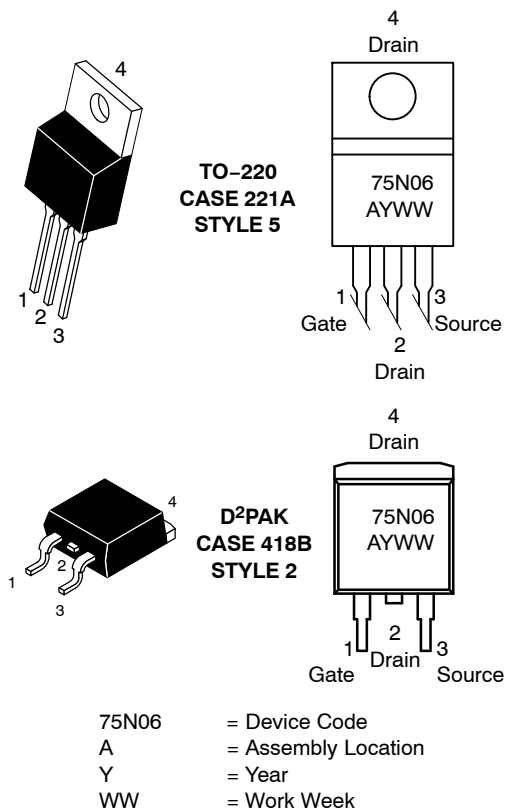
<http://onsemi.com>

75 AMPERES, 60 VOLTS

R_{DS(on)} = 9.5 mΩ



MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NTP75N06, NTB75N06, NTB75N06

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage (Note 1) (V _{GS} = 0 Vdc, I _D = 250 μAdc) Temperature Coefficient (Positive)	V _{(BR)DSS}	60 –	71 73	– –	Vdc mV/°C
Zero Gate Voltage Drain Current (V _{DS} = 60 Vdc, V _{GS} = 0 Vdc) (V _{DS} = 60 Vdc, V _{GS} = 0 Vdc, T _J = 150°C)	I _{DSS}	– –	– –	10 100	μAdc
Gate-Body Leakage Current (V _{GS} = ±20 Vdc, V _{DS} = 0 Vdc)	I _{GSS}	–	–	±100	nAdc

ON CHARACTERISTICS (Note 1)

Gate Threshold Voltage (Note 1) (V _{DS} = V _{GS} , I _D = 250 μAdc) Threshold Temperature Coefficient (Negative)	V _{GS(th)}	2.0 –	2.8 8.0	4.0 –	Vdc mV/°C
Static Drain-to-Source On-Resistance (Note 1) (V _{GS} = 10 Vdc, I _D = 37.5 Adc)	R _{DS(on)}	–	8.2	9.5	mΩ
Static Drain-to-Source On-Voltage (Note 1) (V _{GS} = 10 Vdc, I _D = 75 Adc) (V _{GS} = 10 Vdc, I _D = 37.5 Adc, T _J = 150°C)	V _{DS(on)}	– –	0.72 0.63	0.86 –	Vdc
Forward Transconductance (Note 1) (V _{DS} = 15 Vdc, I _D = 37.5 Adc)	g _{FS}	–	40.2	–	mhos

DYNAMIC CHARACTERISTICS

Input Capacitance	(V _{DS} = 25 Vdc, V _{GS} = 0 Vdc, f = 1.0 MHz)	C _{iss}	–	3220	4510	pF
Output Capacitance		C _{oss}	–	1020	1430	
Transfer Capacitance		C _{rss}	–	234	330	

SWITCHING CHARACTERISTICS (Note 2)

Turn-On Delay Time	(V _{DD} = 30 Vdc, I _D = 75 Adc, V _{GS} = 10 Vdc, R _G = 9.1 Ω) (Note 1)	t _{d(on)}	–	16	25	ns
Rise Time		t _r	–	112	155	
Turn-Off Delay Time		t _{d(off)}	–	90	125	
Fall Time		t _f	–	100	140	
Gate Charge	(V _{DS} = 48 Vdc, I _D = 75 Adc, V _{GS} = 10 Vdc) (Note 1)	Q _T	–	92	130	nC
		Q ₁	–	14	–	
		Q ₂	–	44	–	

SOURCE-DRAIN DIODE CHARACTERISTICS

Forward On-Voltage	(I _S = 75 Adc, V _{GS} = 0 Vdc) (Note 1) (I _S = 75 Adc, V _{GS} = 0 Vdc, T _J = 150°C)	V _{SD}	– –	1.0 0.9	1.1 –	Vdc
Reverse Recovery Time	(I _S = 75 Adc, V _{GS} = 0 Vdc, dI _S /dt = 100 A/μs) (Note 1)	t _{rr}	–	77	–	ns
		t _a	–	49	–	
		t _b	–	28	–	
Reverse Recovery Stored Charge		Q _{RR}	–	0.16	–	μC

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
2. Switching characteristics are independent of operating junction temperatures.

NTP75N06, NTB75N06, NTBV75N06

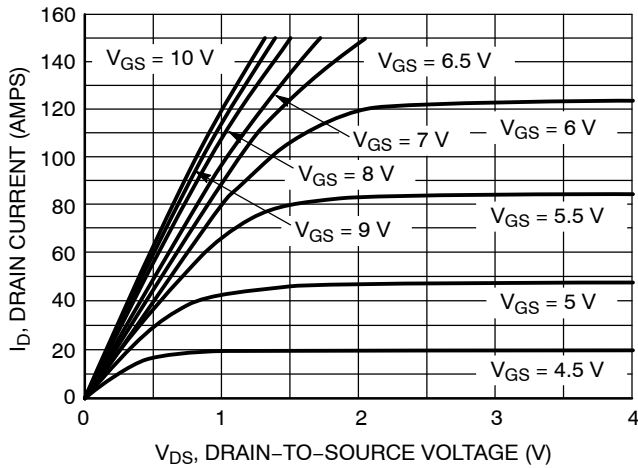


Figure 1. On-Region Characteristics

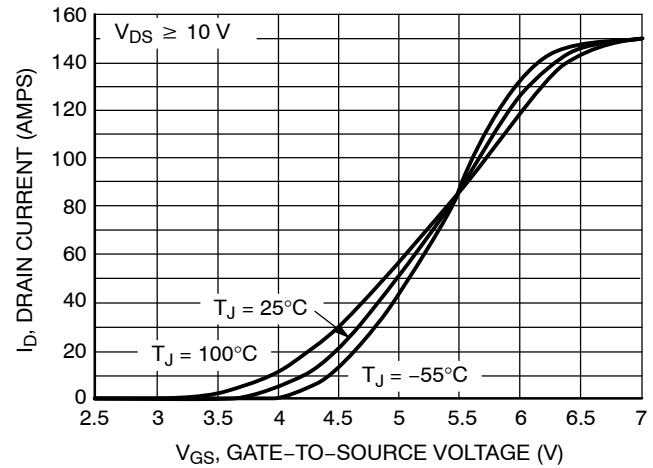


Figure 2. Transfer Characteristics

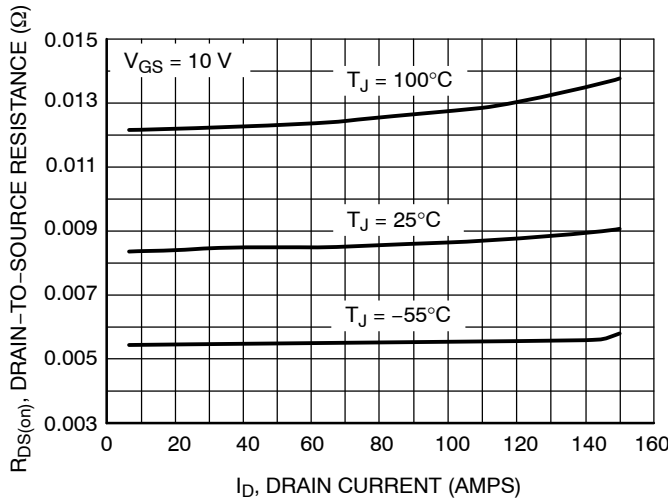


Figure 3. On-Resistance vs. Gate-to-Source Voltage

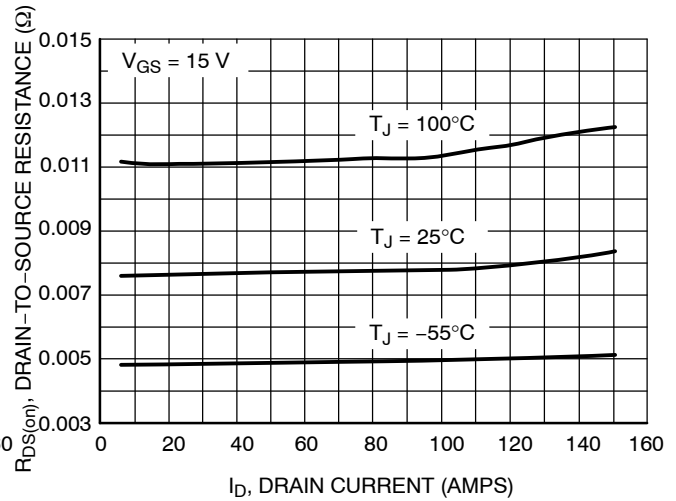


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

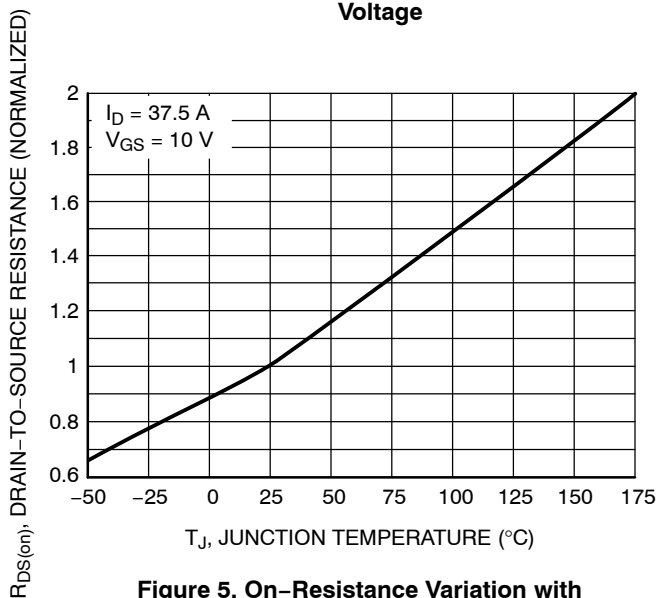


Figure 5. On-Resistance Variation with Temperature

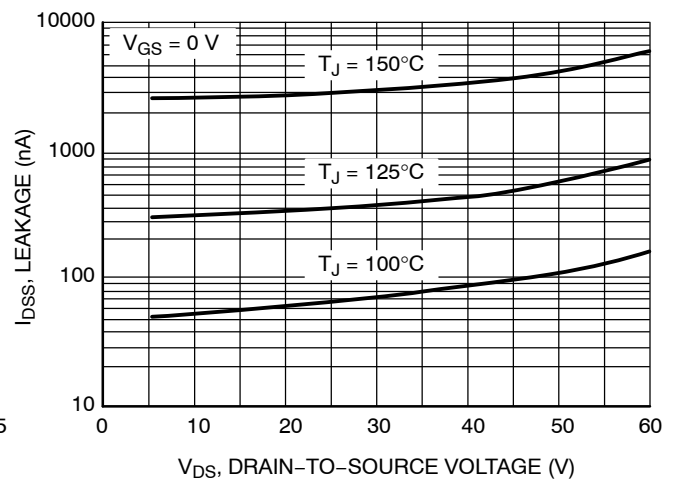


Figure 6. Drain-to-Source Leakage Current vs. Voltage

NTP75N06, NTB75N06, NTB75N06

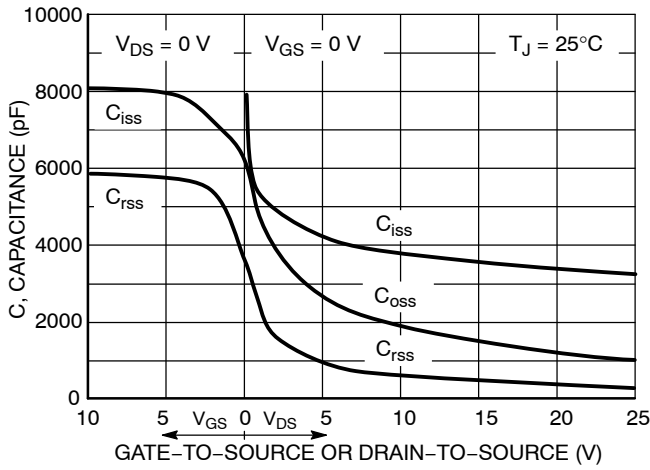


Figure 7. Capacitance Variation

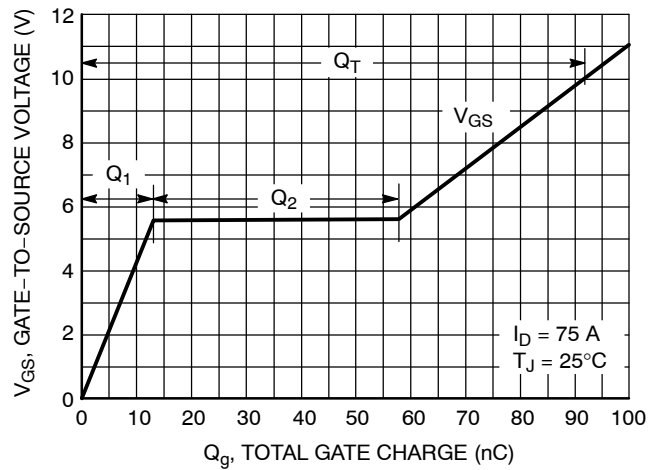


Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

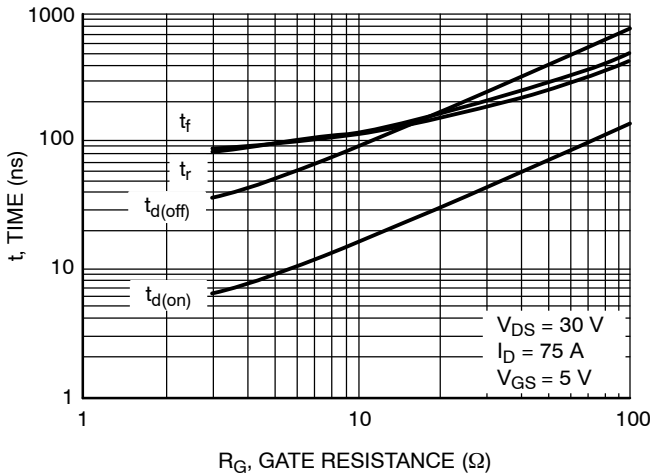


Figure 9. Resistive Switching Time Variations vs. Gate Resistance

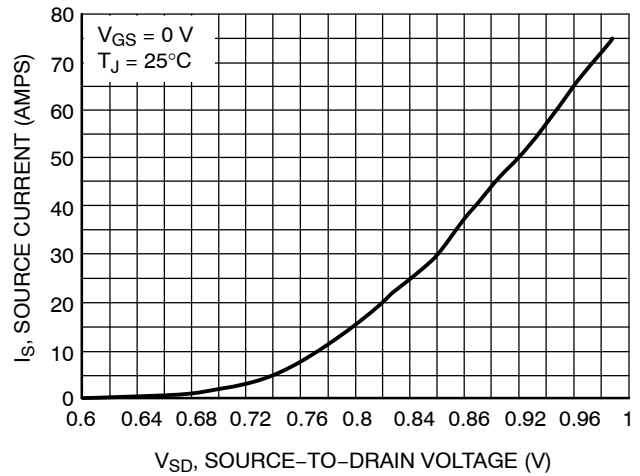


Figure 10. Diode Forward Voltage vs. Current

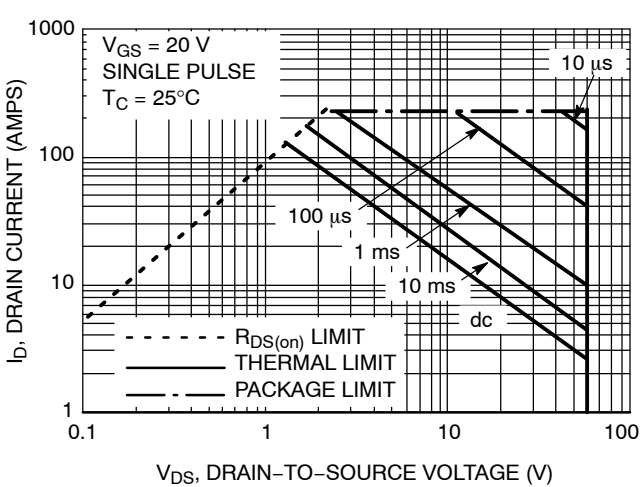


Figure 11. Maximum Rated Forward Biased Safe Operating Area

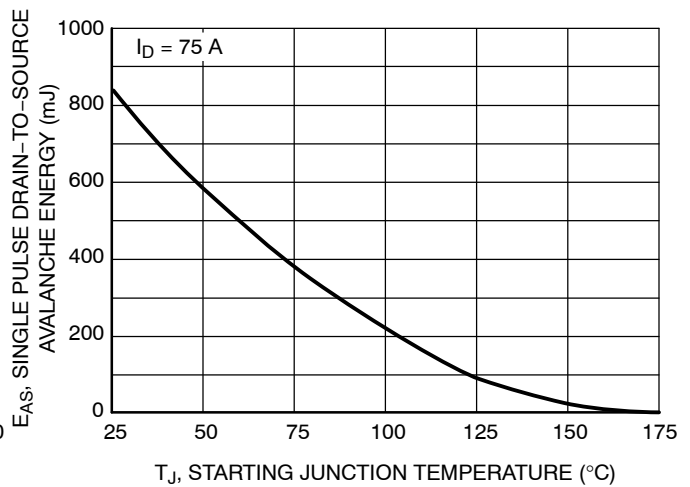


Figure 12. Maximum Avalanche Energy vs. Starting Junction Temperature

NTP75N06, NTB75N06, NTB75N06

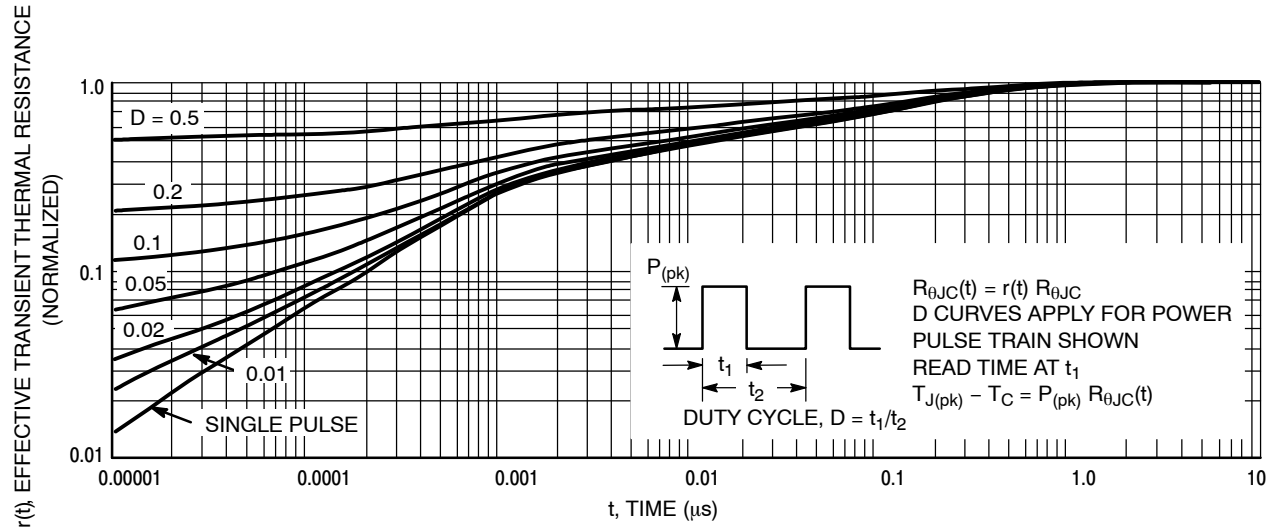


Figure 13. Thermal Response

ORDERING INFORMATION

Device	Package	Shipping [†]
NTP75N06G	TO-220 (Pb-Free)	50 Units/Rail
NTB75N06G	D ² PAK (Pb-Free)	50 Units/Rail
NTB75N06T4G	D ² PAK (Pb-Free)	800 Tape & Reel
NTBV75N06T4G*	D ² PAK (Pb-Free)	800 Tape & Reel

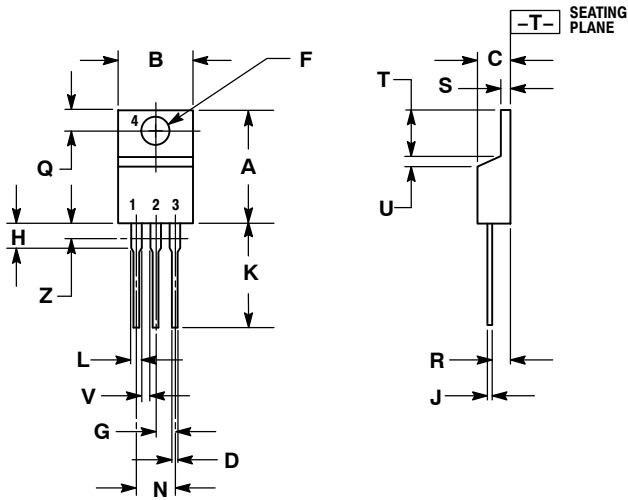
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NTBV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

NTP75N06, NTB75N06, NTB75N06

PACKAGE DIMENSIONS

TO-220
CASE 221A-09
ISSUE AG



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

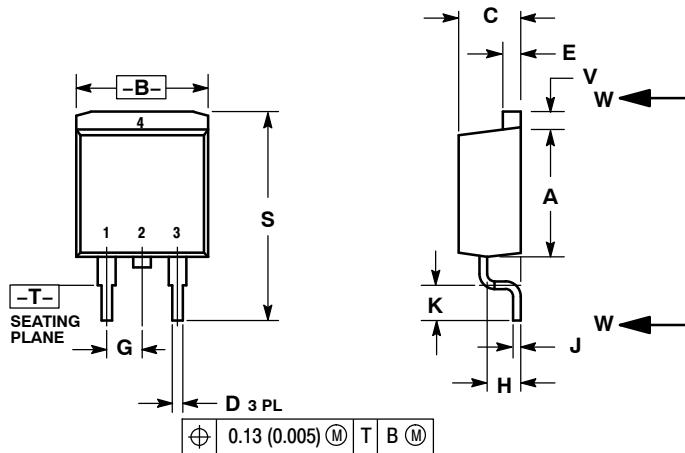
STYLE 5:

- PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

NTP75N06, NTB75N06, NTB75N06

PACKAGE DIMENSIONS

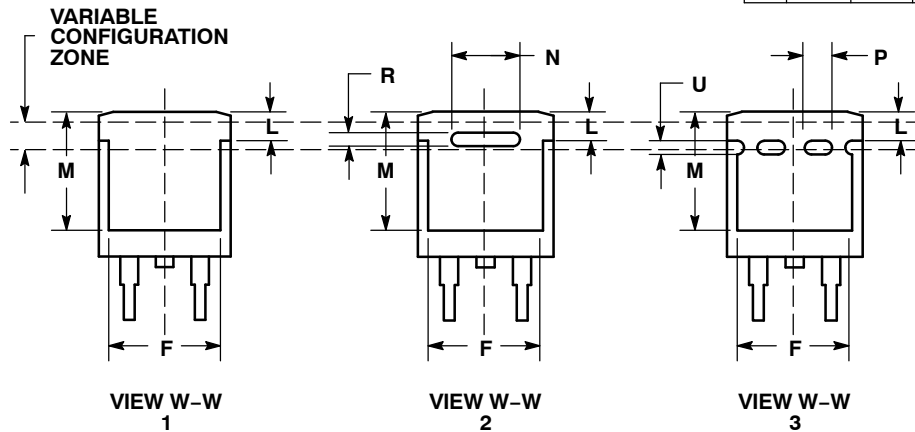
D²PAK CASE 418B-04 ISSUE K



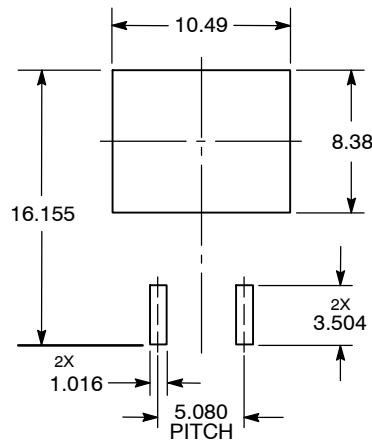
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.340	0.380	8.64	9.65
B	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
E	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54 BSC	
H	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
M	0.280	0.320	7.11	8.13
N	0.197 REF		5.00 REF	
P	0.079 REF		2.00 REF	
R	0.039 REF		0.99 REF	
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40

- STYLE 2:
- PIN 1. GATE
 - DRAIN
 - SOURCE
 - DRAIN



SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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